

Form PTO-1449 INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)				ATTY. DOCKET NO. 3430-0200P		APPLICATION NO. NEW 10/757571	
				APPLICANT Woong-Kwon KIM			
				FILING DATE January 15, 2003		GROUP Unassigned	
U.S. PATENT DOCUMENTS							
CLASSIFICATION	DOCUMENT NUMBER	Kind	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	US 5,994,721	A	1999-11-30	ZHONG et al			
	US 6,162,510	A	12-2000	KASHIWAZAKI et al			
	US 6,104,459	A	2000-08-15	OIKE et al			
	US 5,724,107	A	1998-03-03	NISHIKAWA et al			
	US 6,211,928	B1	2001-04-03	OH et al			
	US 6,221,543	B1	2001-04-24	GUEHLER et al			
	US 5,994,721	A	1999-11-30	ZHONG et al			
	US 6,162,510	A	2000-12-19	KASHIWAZAKI et al			
	US 6,297,862	B1	2001-10-02	MURADE			
	US 6,166,786	A	2000-12-26	OHKUBO et al			
	US 6,327,006	B1	2001-12-04	SATO et al			
	US 6,281,955	B1	2001-08-28	MIDORIKAWA et al			
	US 6,111,623	A	2000-08-29	SATO			
FOREIGN PATENT DOCUMENTS							
Office	DOCUMENT NUMBER	Kind	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION
OTHER DOCUMENTS							
(Include doc. of the author (in CAPITAL LETTERS), title of the article (in appropriate), title of the book, journal, journal, serial, encyclopedia, catalog, etc.) date, page(s), volume-issue number(s), publisher, day and/or country where published.							
	Pichon et al; "Low temperature unhydrogennated in-situ doped polysilicon thin film transistors: Toward a technology for flat panel displays"; Thin Solid Film, Vol. 296, pages 133-136; 1997.						
EXAMINER Hoan Nguyen				DATE CONSIDERED 8/31/04			
WARNING: Initial of inventor considered, whether or not citation is in accordance with 35 U.S.C. 102; show lines through citation if not in accordance and not considered. Include copy of this form with each communication to applicant.							

JAK/PLS/MLR